



ZXT13P20DE6

#### 20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

#### **Features**

- BV<sub>CEO</sub> > -20V
- I<sub>C</sub> = -3.5A Continuous Collector Current
- I<sub>CM</sub> = -10A Peak Pulse Current
- $R_{CE(sat)} = 75m\Omega$  for a Low Equivalent On-Resistance
- Low Saturation Voltage of <-130mV max @ -1A</li>
- h<sub>FE</sub> Characterized up to -10A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

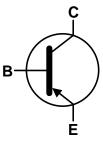
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads;
   Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)

### **Applications**

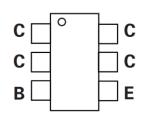
- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control







Device Symbol



Pin-Out Top

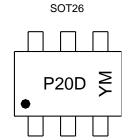
### **Ordering Information** (Notes 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13P20DE6TA	P20D	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



P20D = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	201	5	2016	2017	2018	2019	2020	202	1 20	122	2023	2024	2025
Code	С		D	Е	F	G	Η	I		J	K	L	М
Month	1	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	!	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-25	V
Collector-Emitter Voltage	$V_{CEO}$	-20	V
Emitter-Base Voltage	$V_{EBO}$	-7.5	V
Base Current	I <sub>B</sub>	-500	mA
Continuous Collector Current	Ic	-3.5	Α
Peak Pulse Collector Current	I <sub>CM</sub>	-10	Α

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	W mW/°C	
Power Dissipation	(Note 5)		1.1 8.8		
Linear Derating Factor	(Note 6)	- P <sub>D</sub>	1.7 13.6		
Thermal Desistance, Junction to Ambient	(Note 5)	(Note 5)			
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	73	°C/W	
Thermal Resistance, Junction to Lead (Note 7)		$R_{ heta JL}$	18.61		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

## ESD Ratings (Note 8)

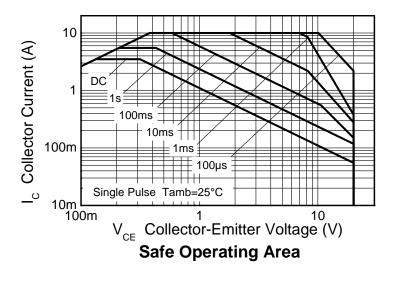
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

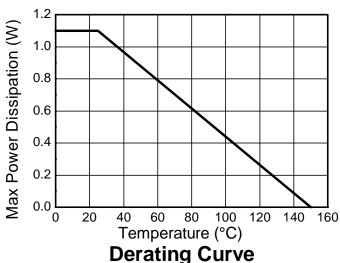
Notes:

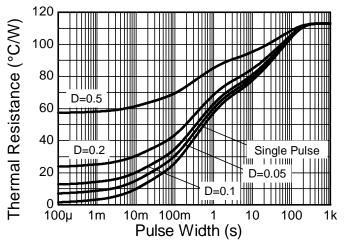
- 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is measured at t ≤ 5 seconds.
  7. Thermal resistance from junction to solder-point (at the end of the collector leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**







**Transient Thermal Impedance** 



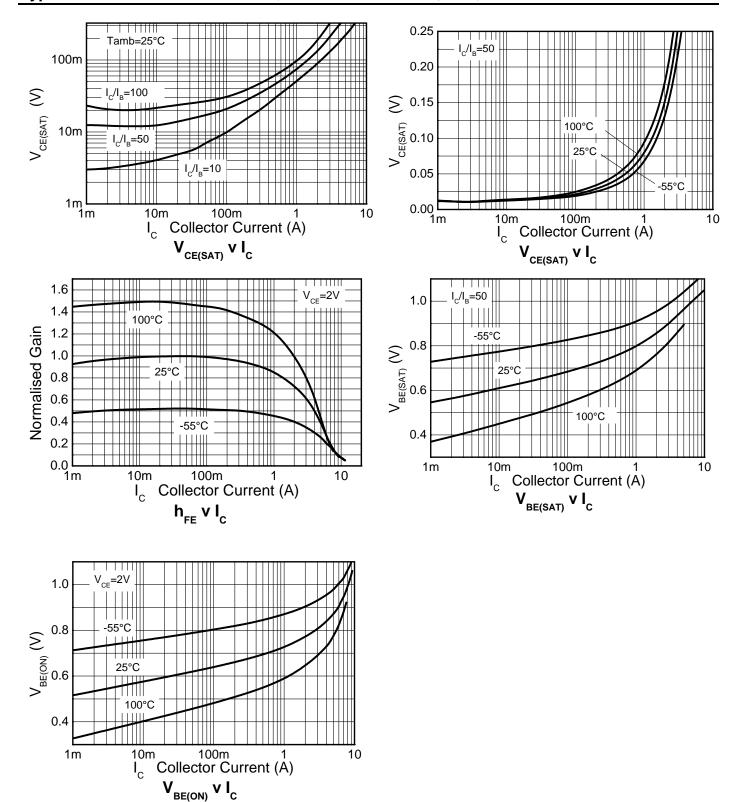
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-25	-55	_	V	$I_{C} = -100 \mu A$	
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-20	-50	_	V	$I_C = -10mA$	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7.5	-8.5		V	$I_E = -100 \mu A$	
Collector-Base Cut-Off Current	I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -20V	
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -6V	
Collector-Emitter Cut-Off Current	I <sub>CES</sub>	_	_	-100	nA	V <sub>CES</sub> = -20V	
ON CHARACTERISTICS (Note 9)							
		300	500	_	_	$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$	
DC Current Gain	h	300	450	900	_	$I_{C} = -1A$ , $V_{CE} = -2V$	
DC Current Gain	h <sub>FE</sub>	150	250		_	$I_C = -3.5A$ , $V_{CE} = -2V$	
		10	_		_	$I_C = -10A$ , $V_{CE} = -2V$	
		_	-10	-15		$I_C = -100 \text{mA}, I_B = -10 \text{mA}$	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	_	-100	-130	mV	$I_C = -1A$ , $I_B = -10mA$	
		_	-165	-250		$I_C = -3.5A$ , $I_B = -350mA$	
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	_	-1.1	V	$I_C = -3.5A$ , $I_B = -350mA$	
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	_	_	-0.9	V	$I_C = -3.5A$ , $V_{CE} = -2V$	
SMALL SIGNAL CHARACTERISTICS	SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f <sub>T</sub>	_	90		MHz	$V_{CE} = -10V$ , $I_{C} = -50mA$ , $f = 50MHz$	
Output Capacitance	C <sub>obo</sub>	_	62		pF	V <sub>CB</sub> = -10V, f = 1MHz	
Turn-On Time	t <sub>(on)</sub>	_	95		ns	$V_{CC} = -10V, I_{C} = -2A$	
Turn-Off Time	t <sub>(off)</sub>		395		ns	$I_{B1} = I_{B2} = -40 \text{mA}$	

Note: 9. Measured under pulsed conditions; pulse width  $\leq 300 \mu s$ , duty cycle  $\leq 2\%$ .



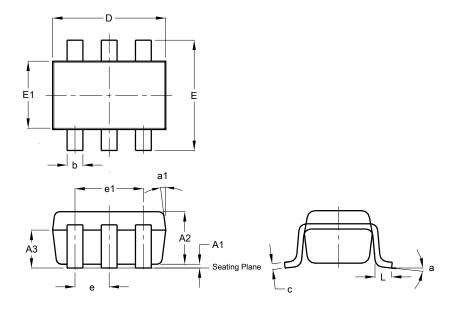
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline**

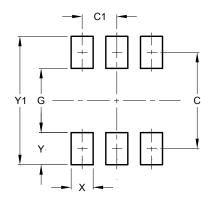
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26							
Dim	Min	Max	Тур					
A1	0.013	0.10	0.05					
A2	1.00	1.30	1.10					
A3	0.70	0.80	0.75					
b	0.35	0.50	0.38					
С	0.10	0.20	0.15					
D	2.90	3.10	3.00					
е	_	-	0.95					
e1	-	-	1.90					
Е	2.70	3.00	2.80					
E1	1.50	1.70	1.60					
L	0.35	0.55	0.40					
а	-	-	8°					
a1	-	-	7°					
All Dimensions in mm								

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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